rfmd.com

RF2861

CDMA LOW NOISE AMPLIFIER/MIXER 900MHz DOWNCONVERTER

Package Style: QFN, 16-pin, 3mm x 3mm



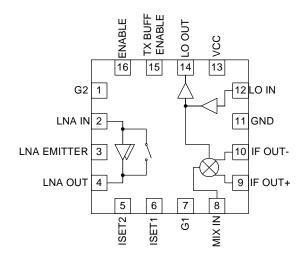


Features

- 3mm x 3mm LNA/Mixer Solution
- Adjustable LNA and Mixer Current/IIP3
- Meets IMD Tests with Three Gain States/Two Logic Control Pins
- Integrated TX LO Buffer Amplifier
- Full ESD Protection on all Pins

Applications

- CDMA/JCDMA Cellular Systems
- CDMA450 Handsets/Data Cards
- AMPS Cellular Systems
- General Purpose LNA and Downconverter
- Commercial and Consumer Systems
- Portable Battery-Powered Equipment



Functional Block Diagram

Product Description

The RF2861 is a receiver front-end for CDMA cellular applications, including JCDMA and CDMA450. It is designed to amplify and downconvert RF signals, using a three gain state LNA to obtain 17dB of stepped gain control. Features include digital control of LNA gain and power down mode, along with an integrated TX LO buffer amplifier. Another feature of the chip is adjustable IIP3 of the LNA and mixer using off-chip current setting resistors to allow for minimum DC current consumption. Noise figure, IIP3, and other specs are designed to be compatible with the TIA/EIA 98D standard for CDMA cellular communications. The IC is manufactured on an advanced Silicon Germanium Bi-CMOS process and is in a 3mm x 3mm, 16-pin, OFN.

Ordering Information

☐ GaAs HBT☐ GaAs MESFE

RF2861SQ Sample bag with 25 pieces
RF2861SR 7" Reel with 100 pieces
RF2861TR7 7" Reel with 2500 pieces
RF2861PCK-410 460MHz to 900MHz PCBA with 5-piece sample bag

| 0 | Optimum Technology Matching® Applied | | | | | | | |
|---|--------------------------------------|--------------|-------------|--|--|--|--|--|
| | ✓ SiGe BiCMOS | ☐ GaAs pHEMT | ☐ GaN HEMT | | | | | |
| Γ | ☐ Si BiCMOS | ☐ Si CMOS | ☐ BiFET HBT | | | | | |
| | ☐ SiGe HBT | ☐ Si BJT | LDMOS | | | | | |

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Absolute Maximum Ratings

| Parameter | Rating | Unit |
|-------------------------------|--------------|-----------------|
| Supply Voltage | -0.5 to +5.0 | V _{DC} |
| Input LO and RF Levels | +6 | dBm |
| Operating Ambient Temperature | -40 to +85 | °C |
| Storage Temperature | -40 to +150 | °C |



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2002/95/EC.

| Dovemeter | | Specification | | Unit | Condition | | |
|----------------------------------|-------|---------------|------|------|--|--|--|
| Parameter | Min. | Тур. | Max. | Unit | | | |
| Overall | | | | | T = 25°C, V _{CC} = 2.75V | | |
| RF Frequency Range | | 460 to 900 | | MHz | | | |
| IF Frequency Range | 0.1 | | 400 | MHz | | | |
| Power Supply | | | | | | | |
| Supply Voltage | 2.65 | 2.75 | 3.15 | V | | | |
| Logic High | 1.8 | | | V | | | |
| Logic Low | | | 0.4 | V | | | |
| Cellular CDMA Band JCDMA Band | | | | | Freq = 869MHz to 894MHz Freq = 832MHz to 870MHz | | |
| LNA (High Gain) | | | | | LNA 50Ω match | | |
| Gain | 13.0 | 14.5 | 16.0 | dB | | | |
| Noise Figure | | 1.1 | 1.3 | dB | | | |
| Input IP3 | 9.0 | 11.0 | | dBm | | | |
| Current | | 7.0 | | mA | | | |
| Isolation | 18.5 | | | dB | | | |
| LNA (Mid Gain) | | | | | | | |
| Gain | 4.0 | 6.0 | 7.0 | dB | | | |
| Noise Figure | | 3.0 | 3.3 | dB | | | |
| Input IP3 | 7.0 | 9.0 | | dBm | | | |
| Current | | 3.5 | | mA | | | |
| Isolation | 12.5 | | | dB | | | |
| LNA (Low Gain) | | | | | | | |
| Gain | -4.0 | -2.5 | -1.0 | dB | | | |
| Noise Figure | | 2.5 | 4.0 | dB | | | |
| Input IP3 | +25.0 | +27.0 | | dBm | | | |
| Current | | 0 | | mA | | | |
| Isolation | 1.0 | | | dB | | | |
| Mixer - CDMA/JCDMA/FM | | | | | IF tune set for nominal mixer gain, high IIP3 | | |
| Gain | 9.0 | 10.5 | 12.0 | dB | | | |
| Noise Figure | | 7.5 | 8.0 | dB | 184MHz IF (NF = 8.3dB, 85MHz IF) | | |
| Input IP3 | +6.0 | +8.5 | | dBm | | | |
| LO to RF Isolation | 36 | | | dB | LO = 1064MHz | | |



| Davamatav | Specification | | | Unit | Condition | | |
|--|---------------|-------|------|------|---|--|--|
| Parameter | Min. | Тур. | Max. | | Condition | | |
| Mixer - CDMA/JCDMA/FM | | | | | IF tune set for high mixer gain, nominal IIP3 | | |
| Gain | | 13.0 | | dB | | | |
| Noise Figure | | 7.5 | | dB | 184MHz IF (NF = 8.3dB, 85MHz IF) | | |
| Input IP3 | | +6.5 | | dBm | | | |
| LO to RF Isolation | 36 | | | dB | LO = 1064MHz | | |
| Cascade - High Gain | | | | | | | |
| Current | | 25 | 30 | mA | TX LO Buffer Off | | |
| Cellular CDMA Band JCDMA Band, cont'd | | | | | | | |
| Other | | | | | | | |
| LO-IF Isolation | 30 | | | dB | LO = 1064MHz | | |
| RF-IF Isolation | 45 | | | dB | | | |
| LNA Out to Mixer In Isolation | 45 | | | dB | | | |
| LO-LNA In Isolation, Any State | 40 | | | dB | LO = 1064MHz | | |
| Control Lines | | | | | | | |
| Input Capacitance | | | 1 | pF | G1, G2, ENABLE, TX BUFF ENABLE | | |
| Local Oscillator Input | | | | · | | | |
| Cellular - CDMA or FM | | | | | | | |
| Input Power | -10 | -4 | 0 | dBm | | | |
| Input Frequency | 685 | | 710 | MHz | IF = 184MHz | | |
| | 1053 | | 1078 | MHz | IF = 184MHz | | |
| | 784 | | 809 | MHz | IF = 85MHz | | |
| | 954 | | 979 | MHz | IF = 85MHz | | |
| Cellular - JCDMA | | | | | | | |
| Input Power | -10 | -4 | 0 | dBm | | | |
| Input Frequency | 722 | | 760 | MHz | IF = 110MHz | | |
| | 942 | | 980 | MHz | IF = 110MHz | | |
| CDMA450 | | | | | | | |
| Input Power | -10 | -4 | 0 | dBm | | | |
| Input Frequency | 505 | | 575 | MHz | IF = 85MHz | | |
| CDMA450 Band | | | | | Freq = 463MHz to 467MHz | | |
| LNA (High Gain) | | | | | LNA 50Ω match | | |
| Gain | | 15.0 | | dB | | | |
| Noise Figure | | 1.4 | | dB | | | |
| Input IP3 | | +8.0 | | dBm | | | |
| Current | | 8.7 | | mA | | | |
| Isolation | 18.5 | | | dB | | | |
| LNA (Mid Gain) | | | | | | | |
| Gain | | +2.5 | | dB | | | |
| Noise Figure | | 2.9 | | dB | | | |
| Input IP3 | | +14.0 | | dBm | | | |
| Current | | 4.7 | | mA | | | |
| Isolation | 12.5 | | | dB | | | |

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| Baramatar - | | Specification | n | Unit | Condition |
|--|------|---------------|------|------|---|
| Parameter | Min. | Тур. | Max. | Unit | Condition |
| LNA (Low Gain) | | _ | | | |
| Gain | | -4.0 | | dB | |
| Noise Figure | | 4.0 | | dB | |
| Input IP3 | | +25.0 | | dBm | |
| Current | | 0 | | mA | |
| Isolation | 1.0 | | | dB | |
| Mixer | | | | | IF tune set for high mixer gain, nominal IIP3 |
| Gain | | 12.0 | | dB | |
| Noise Figure | | 7.5 | | dB | |
| Input IP3 | | 5.0 | | dBm | |
| LO to RF Isolation | 36 | | | dB | LO = 549MHz |
| CDMA450 Isolation | | | | | |
| LO-IF Isolation | 25 | | | dB | LO = 549MHz |
| RF-IF Isolation | 40 | | | dB | |
| LNA Out to Mixer In Isolation | 40 | | | dB | |
| LO-LNA In Isolation, Any State | 30 | | | dB | LO = 549MHz |
| TX (Local Oscillator) Buffer Output | | | | | |
| Cellular - CDMA or FM | | | | | |
| Output Power | -7 | -5 | -3 | dBm | Single-ended 50Ω load |
| Output Frequency | 685 | | 710 | MHz | IF = 184MHz |
| | 1053 | | 1078 | MHz | IF = 184MHz |
| | 784 | | 809 | MHz | IF = 85MHz |
| | 954 | | 979 | MHz | IF = 85MHz |
| Current Consumption | | 2 | | mA | |
| Cellular - JCDMA | | | | | |
| Output Power | -7 | -5 | -3 | dBm | Single-ended 50Ω load |
| Output Frequency | 722 | | 760 | MHz | IF = 110MHz |
| | 942 | | 980 | MHz | IF = 110MHz |
| Current Consumption | | 2 | | mA | |
| CDMA450 | | | | | |
| Output Power | -7 | -5 | -3 | dBm | Single-ended 50Ω load |
| Output Frequency | 505 | | 575 | MHz | IF = 85MHz |
| Current Consumption | | 2 | | mA | |



Gain Control Logic Table

| Gain State | ENABLE | G1 | G2 |
|----------------------|--------|-----------|----|
| High Gain | 1 | 0 | 0 |
| Mid Gain | 1 | 1 | 0 |
| Low Gain | 1 | 1 | 1 |
| Low Gain (alternate) | 1 | 0 | 1 |

NOTE: All IDC current numbers include bias circuitry current of 1.5mA to 2.0mA (dependent on mode). TX Buffer On: Add 2mA to total current.

Cell Band Cascaded Performance High Mixer Gain Nominal IIP3

(Typical Values for $V_{CC} = 2.75V$)

| Parameter | CELL CDMA | | | | | |
|--------------------|-----------------|----------------|----------------|--|--|--|
| | LNA (High Gain) | LNA (Mid Gain) | LNA (Low Gain) | | | |
| Cascaded: | | | | | | |
| Gain (dB) | 25.0 | 16.5 | 8.0 | | | |
| Noise Figure (dB) | 2.1 | 6.3 | 12.5 | | | |
| Input IP3 (dBm) | -5.6 | +2.0 | +11.4 | | | |
| Total Current (mA) | 25.0 | 21.5 | 18.0 | | | |

VIOTES:

- 1. Assumes 2.5dB image filter insertion loss. The TX Buffer is off.NOTE:
- 2. All total current numbers include bias circuitry current of 1.5 mA to 2.0 mA (dependent on mode).

Cell Band Cascaded Performance Nominal Mixer Gain High IIP3

(Typical Values for $V_{CC} = 2.75V$)

| Parameter | CELL CDMA | | | | | |
|--------------------|-----------------|----------------|----------------|--|--|--|
| | LNA (High Gain) | LNA (Mid Gain) | LNA (Low Gain) | | | |
| Cascaded: | | | | | | |
| Gain (dB) | 22.5 | 14.0 | 5.5 | | | |
| Noise Figure (dB) | 2.1 | 6.3 | 12.5 | | | |
| Input IP3 (dBm) | -3.7 | +3.5 | +13.3 | | | |
| Total Current (mA) | 25.0 | 21.5 | 18.0 | | | |

NOTE: Assumes 2.5dB image filter insertion loss. The TX Buffer is off.

CDMA450 Band Cascaded Performance

(Typical Values for $V_{CC} = 2.75V$)

| Parameter | CDMA450 | | | | | |
|--------------------|-----------------|----------------|----------------|--|--|--|
| | LNA (High Gain) | LNA (Mid Gain) | LNA (Low Gain) | | | |
| Cascaded: | | | | | | |
| Gain (dB) | 24.5 | 12.0 | 5.5 | | | |
| Noise Figure (dB) | 2.2 | 8.5 | 14.0 | | | |
| Input IP3 (dBm) | -7.6 | +4.5 | +11.3 | | | |
| Total Current (mA) | 29.5 | 25 | 21 | | | |

NOTE: Assumes 2.5dB image filter insertion loss. The TX Buffer is off.



Pin Names and Descriptions

| Pin | Function | Туре | Description | Interface Schematic |
|-----|-------------|------|--|---------------------|
| 1 | G2 | DI | Gain control logic input. See logic control table. | . 1 |
| | | | | G2 O |
| | | | | |
| 2 | LNA IN | Al | Cellular LNA input. | V _{cc} |
| | | | | OLNA OUT |
| | | | | LNA INO |
| | | | | LNA EMITTER |
| 3 | LNA EMITTER | AO | Cellular LNA emitter. A small inductor connects this pin to ground. Cellular LNA gain can be adjusted by the inductance. | See pin 2. |
| 4 | LNA OUT | AO | Cellular LNA output. Simple external L-C components required for | See pin 2. |
| _ | ICETO | 40 | matching and VCC supply. An external resistor connected to this pin sets the current of the | |
| 5 | ISET2 | AO | mixer. Increasing resistance decreases current. | |
| 6 | ISET1 | AO | An external resistor connected to this pin sets the current of the LNA. Increasing resistance decreases current. | |
| 7 | G1 | DI | Gain control logic input. See logic control table. | |
| | | | | G1 C |
| | | | | |
| 8 | MIX IN | Al | Cellular mixer RF single-end input. | |
| | | | | MIX INO |
| | | | | Φ |
| | IE OUT : | 40 | CDMA IF output. Open collector. | <u></u> |
| 9 | IF OUT+ | AO | CDMA IF output. Open collector. | IF OUT+ IF OUT- |
| | | | | |
| | | | | |
| | | | | <u> </u> |
| 10 | IF OUT- | AO | CDMA IF output. Open collector. | See pin 9. |
| 11 | GND | Р | Ground. | |
| 12 | LO IN | Al | LO single-end input. Matched to 50Ω . | LO INO + |
| | | | | > 70 Ω |
| | | | | |
| 13 | vcc | Р | LO amplifier VCC external bypass capacitor may be required. | _ |
| 14 | LO OUT | AO | LO output. Internal DC block. Drives 50Ω . | |
| 15 | TX BUFF | DI | Logic input. High enables TX LO output buffer amplifiers. | _ |
| | ENABLE | | | TX BUFF ENABLE O |
| | | | | |



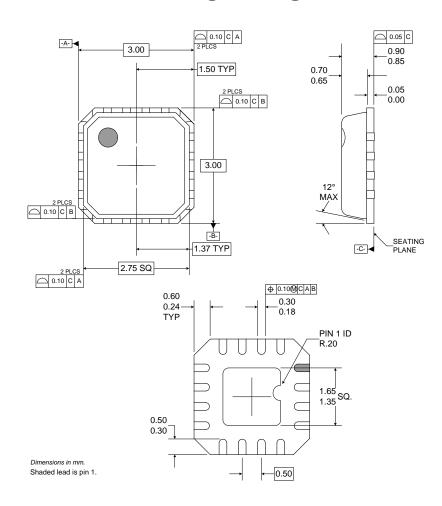
| Pin | Function | Туре | Description | Interface Schematic |
|-------------|----------|------|---|---------------------|
| 16 | ENABLE | DI | Logic input. Low level powers down the IC. | ENABLE O |
| Pkg Base | GND | Р | Ground connection. The backside of the package should be soldered to a top side ground pad which is connected to the ground plane with multiple vias. | |

Legend:

DI = Digital Input from Baseband ChipAI = Analog Input

 $P = V_{CC}$ or GNDAO = Analog Output

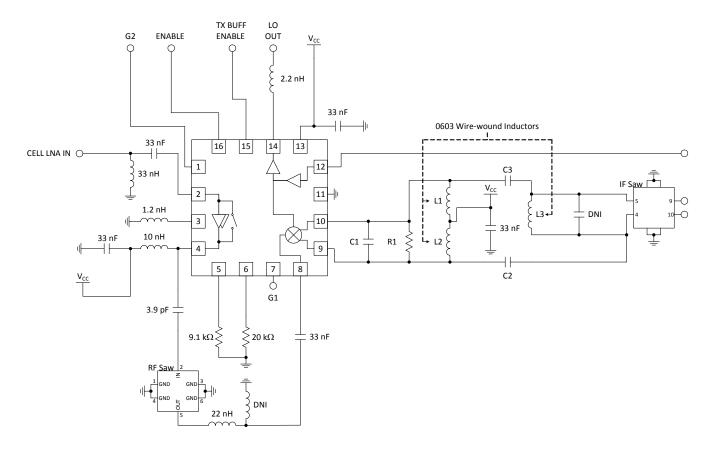
Package Drawing





Application Schematic

Differential IF Matching

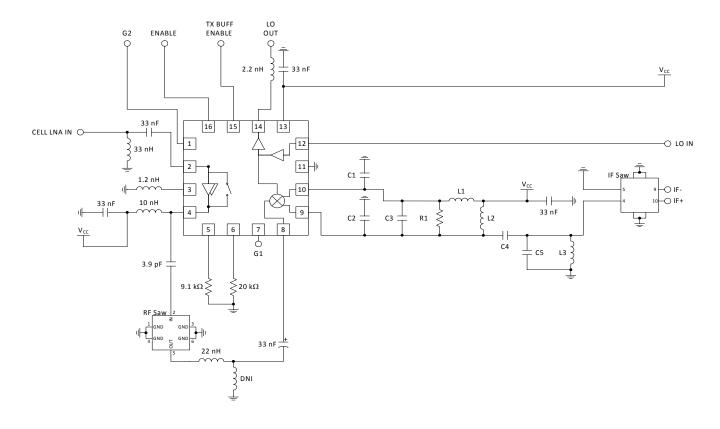


| | C1 | R1 | L1 | L2 | C2 | C3 | L3 | IF SAW FILTER |
|-------------------------------|-------|-------|------|------|-------|-------|-------|---------------|
| 85MHz IF (LO Freq = 965MHz) | 22pF | 2.7kΩ | 72nH | 72nH | 5.1pF | 5.1pF | 220nH | SAWTEK 855845 |
| 184MHz IF (LO Freq = 1064MHz) | 5.0pF | 2.7kΩ | 55nH | 55nH | 10pF | 10pF | 43nH | EPCOS B4955 |



Application Schematic

Single-End Matching

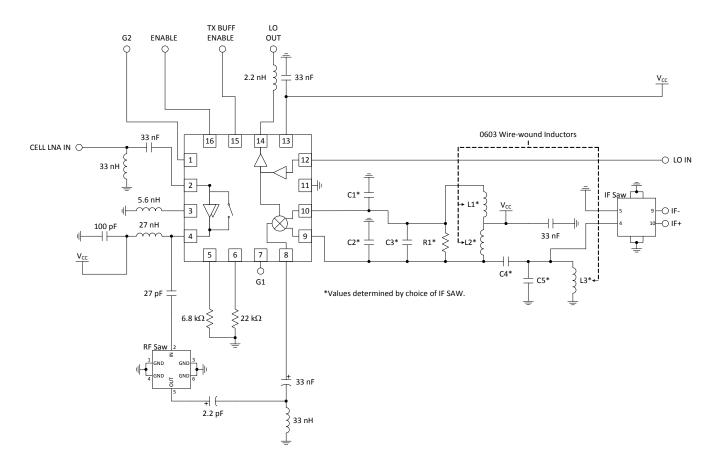


| | C1 | C2 | C3 | R1 | L1 | L2 | C4 | C5 | L3 | IF SAW FILTER |
|-------------------------------|------|------|-----------|------------------|------|------|-------|-----|-------|---------------|
| 85MHz IF (LO Freq = 965MHz) | 43pF | 43pF | DNI | 2.7 k Ω | 72nH | 72nH | 5.1pF | DNI | 220nH | SAWTEK 855845 |
| 184MHz IF (LO Freq = 1064MHz) | 13pF | 13pF | DNI | 2.7kΩ | 55nH | 55nH | 10pF | DNI | 43nH | EPCOS B4955 |



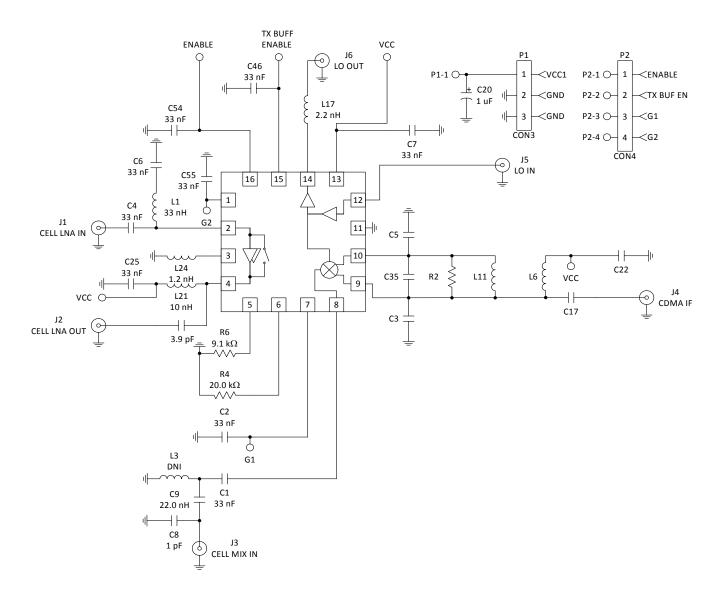
Application Schematic

Single-End Matching CDMA450 Band





Evaluation Board Schematic

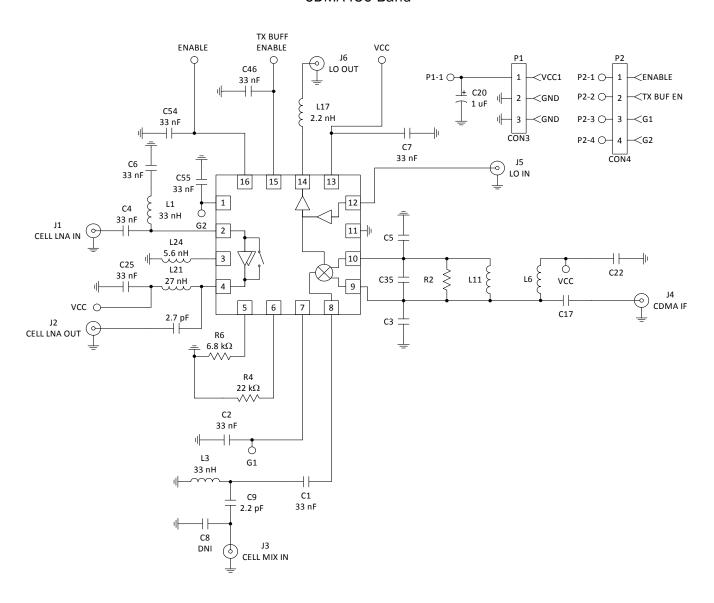


| | С3 | C 5 | C35 | R2 | L11 | L6 | C22 | C17 |
|-------------------------------|------|------------|-----|------------------|-------|-------|------|------|
| 85MHz IF (LO Freq = 965MHz) | 47pF | 47pF | DNI | 5.1 k Ω | 150nH | 180nH | 33nF | 8pF |
| 184MHz IF (LO Freq = 1064MHz) | 13pF | 13pF | DNI | 2.7kΩ | 82nH | 150nH | 33nF | 11pF |



Evaluation Board Schematic

CDMA450 Band

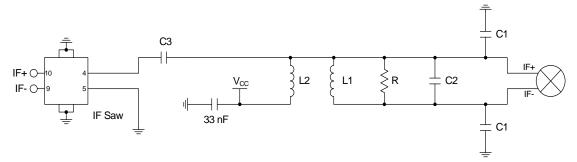


| | C3 | C5 | C35 | R2 | L11 | L6 | C22 | C17 | |
|-----------------------------|------|------|-----|------------------|------|-------|------|------|--|
| 85MHz IF (LO Freq = 549MHz) | 91pF | 91pF | DNI | 6.8 k Ω | 68nH | 270nH | 33nF | 27pF | |



IF Output Interface Network

Single-End IF Matching



L1, C2, and R form a current combiner which performs a differential to single-ended conversion at the IF frequency and sets the output impedance. In most cases, the resonance frequency is independent of R and can be set according to the following equation:

$$f_{IF} = \frac{1}{2\pi \sqrt{\frac{L1}{2}(C_1 + 2C_2 + C_{EQ})}}$$

Where C_{EQ} is the equivalent stray capacitance and capacitance looking into pins 9 and 10. An average value to use for C_{EQ} is 2.5pF.

R can then be used to set the output impedance according to the following equation:

$$R = \left(\frac{1}{4 \cdot R_{OUT}} - \frac{1}{R_P}\right)^{-1}$$

where R_{OUT} is the desired output impedance and R_P is the parasitic equivalent parallel resistance of L1.

 C_2 should first be set to 0 and C1 should be chosen as high as possible (not greater than 39pF), while maintaining an R_P of L1 that allows for the desired R_{OUT} . If the self-resonant frequencies of the selected C1 produce unsatisfactory linearity performance, their values may be reduced and compensated for by including C2 capacitor with a value chosen to maintain the desired F_{IF} frequency.

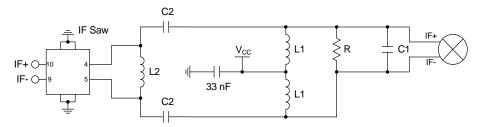
L2 and C3 serve dual purposes. L2 serves as an output bias choke, and C3 serves as a series DC block.

In addition, L2 and C3 may be chosen to form an impedance matching network if the input impedance of the IF filter is not equal to R_{OUT} . Otherwise, L2 is chosen to be large (suggested 120nH) and C3 is chosen to be large (suggested 22nF) if a DC path to ground is present in the IF filter, or omitted if the filter is DC-blocked.

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Differential IF Matching



L1 and C1 are chosen to resonate at the desired IF frequency. C1 can be omitted and the value of L1 increased and utilized solely as a choke to provide V_{CC} to the open-collector outputs, but it is strongly recommended that at least some small-valued C1 (a few pF) be retained for better mixer linearity performance. R is normally selected to match the input impedance of the IF filter. However, mixer performance can be modified by selecting an R value that is different from the IF filter input impedance, and inserting a conjugate matching network between the Resistive Output Network and the IF filter.

C2 serve dual purposes. C2 serves as a series DC block when a DC path to ground is present in the IF filter. In addition, C2 may be chosen to improve the combine performance of the mixer and IF filter. L2 should choose to resonate with the internal capacitance of the SAW filter. Usually, SAW filter has some capacitance. Otherwise, L2 could be eliminated.

A practical approach to obtain the differential matching is to tune the mixer to the correct load point for gain, IIP3, and NF using the single-end current combiner method. Second, use the component values found in the single-end approach as starting point for the differential matching. The two-shunt capacitors in the single-end could be converted in a parallel capacitor and the parallel inductor in the single-end need to be converted in two-choke inductor. Third, set the DC block capacitors (C2) in the differential-end matching to a high value (100pF) and retune the resonate circuit (C1 and L1) and the resistor (R) for optimal performance. After optimal performance is achieved and if performance is not satisfactory, decrease the series capacitors until optimal performance is achieved.



PCB Design Requirements

PCB Surface Finish

The PCB surface finish used for RFMD's qualification process is electroless nickel, immersion gold. Typical thickness is 3μ inch to 8μ inch gold over 180μ inch nickel.

PCB Land Pattern Recommendation

PCB land patterns are based on IPC-SM-782 standards when possible. The pad pattern shown has been developed and tested for optimized assembly at RFMD; however, it may require some modifications to address company specific assembly processes. The PCB land pattern has been developed to accommodate lead and package tolerances.

PCB Metal Land Pattern

